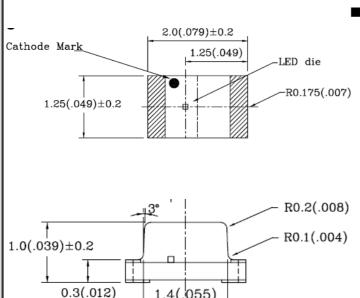
0805 Package Bluish Green SMD Chip LED Lamps (1.0mm Height)

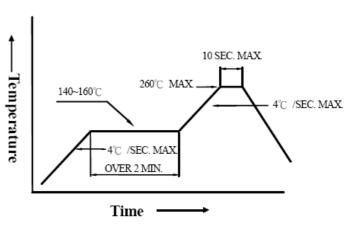
Part Number: AL-HG435A

Package outlines & Re-flow Profile



1.4(.055)

■Reflow Temp/Time

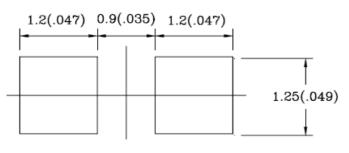


■Soldering iron

Basic spec is ≤ 5sec when 260°C. If temperature is higher, time should be shorter (+10 $^{\circ}$ C \rightarrow -1sec).Power dissipation of iron should be smaller than 15W, and temperatures should be controllable .Surface temperature of the device should be under 230°C .

Cathode Mark		00.1
cathode mark		1 1
	0.4(.016)	-0.4(.016)

For Reflow Soldering



ITEM	MATERIALS
Resin (mold)	Ероху
Lens color	Water Clear
Printed circuit board	BT
Dice	InGaN
Emitted color	Bluish Green

NOTES:

- 1. All dimensions are in millimeters (inches);
- 2. Tolerances are ± 0.1 mm (0.004inch) unless otherwise noted.

Part Number: AL-HG435A

ELECTRO-OPTICAL CHARACTER		(T _A =25°℃)		
Parameter	Test Condition	Symbol	Value	Unit
Viewing angle at 50% l _√	I _F =10mA	2 0 1/2	120	Deg
Forward voltage (Ty	/p.) I _F =20mA	V _F	3.5	V
	ax.)	V F	3.5 4.0 63.0 120.0 505	'
'	lin.)	1	63.0	mad
Luminous intensity (Ty	/p.)	l _V	120 3.5 4.0 63.0 120.0	mcd
Movelenath	I _F =20mA	λр	505	nm
Wavelength	IF-ZUITIA	λd	120 3.5 4.0 63.0 120.0 505 505±5 30	nm
Spectral Line Half-Width	I _F =20mA	$\triangle \lambda$	30	nm
Peak pulsing current (1/10 duty f=1kHz)		I _{FP}	100	mA

Absolute maximum ratings			T _A =25°C)
Parameter	Symbol	Value	Unit
Forward current	l _F	30	mA
Reverse voltage	V _R	5	V
Reverse current	I _R	100	μΑ
Power Dissipation	P _D	100	mW
Operating temperature range	Тор	-25 ~+80	$^{\circ}\mathbb{C}$
Storage temperature range	Tstg	-30 ~+85	$^{\circ}\!\mathbb{C}$
Lead soldering temperature	260	0°C For 5 Seconds	

Part Number: AL-HG435A

Test items and results of reliability

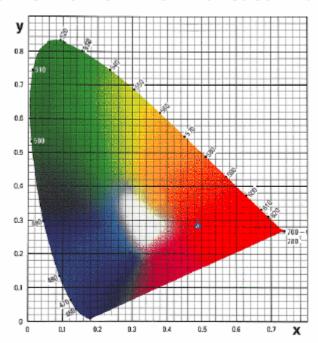
Classification	Test Item	Reference Standard	Test Conditions	Result
Endurance Test	Operation Life	MIL-STD-750:1026 MIL-STD-883:1005 JIS-C-7021 :B-1	Connect with a power If=20mA Ta=Under room temperature Test time=1,000hrs	0/20
	High Temperature High Humidity Storage	MIL-STD-202:103B JIS-C-7021 :B-11	Ta=+65°C±5°C RH=90%-95% Test time=240hrs	0/20
	High Temperature Storage	MIL-STD-883:1008 JIS-C-7021 :B-10	High Ta=+85°ℂ±5°ℂ Test time=1,000hrs	0/20
	Low Temperature Storage	JIS-C-7021 :B-12	Low Ta=-35°C±5°C Test time=1,000hrs	0/20
Environmental Test	Temperature Cycling	MIL-STD-202:107D MIL-STD-750:1051 MIL-STD-883:1010 JIS-C-7021 :A-4	-35°C ~ +25°C ~ +85°C ~ +25°C 60min 20min 60min 20min Test Time=5cycle	0/20
	Thermal Shock	MIL-STD-202:107D MIL-STD-750:1051 MIL-STD-883:1011	-35°C±5°C ~+85°C±5°C 20min 20min Test Time=10cycle	0/20
	Solder Resistance	MIL-STD-202:201A MIL-STD-750:2031 JIS-C-7021 :A-1	Preheating: 140℃-160℃,within 2 minutes. Operation heating: 260℃(Max.), within 10seconds. (Max.)	0/20

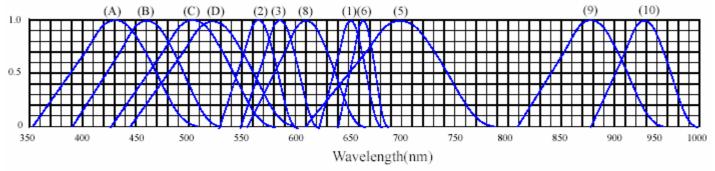
^{*}Refer to reliability test standard specification for in this line.

Part Number: AL-HG435A

Typical Optical-Electrical Characteristic Curves

◆ TYPICAL ELECTRICAL-OPTICAL CHARACTERISTICS CURVES





RELATIVE INTENSITY VS. WAVELENGTH(λp)

- (1) GaAsP/GaAs 655nm/Red
- (2) GaP 568nm/ Yellow Green
- (3) GaAsP/GaP 585nm/Yellow
- (4) GaAsP/GaP 635nm/Orange & Hi-Eff Red
- (5) GaP 700nm/Bright Red
- (6) GaAlAs/GaAs 660nm/Super Red
- (8) GaAsP/GaP 610nm/Super Red

- (9)- GaAlAs 880nm
- (10)-GaAs/GaAs&GaAlAs/GaAs 940nm
- (A)- GaN 430nm/Blue
- (B)- InGaN 470nm/Blue
- (C)- InGaN 502nm/Ultra Green
- (D)- InGaN 523nm/Ultra Green

Part Number: AL-HG435A

Typical Optical-Electrical Characteristic Curves

♦ CHARACTERISTICS DIAGRAMS

